



**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

**In re Application of**

Noboru Ichinose, et al.

**Serial No.:** 10/567,369

**Group Art Unit:** 2814

**Filed:** May 15, 2006

**Examiner:** Sarah Kate Salerno

**For:** SEMICONDUCTOR LAYER WITH A  $\text{Ga}_2\text{O}_3$  SYSTEM

Honorable Commissioner of Patents  
Alexandria, VA 22313 – 1450

**AMENDMENT UNDER 37 C.F.R. §1.111**

Sir:

In response to the Office Action dated November 18, 2009, please Amend the above-identified application as follows:

**INTRODUCTORY COMMENTS**

Claims 1, 4, 6, 9-13, 15, and 21 are all the claims presently pending in the application.

Claims begin on page 2 of this paper. No new matter is added.

Remarks begin at page 4 of this paper.

Exhibit 1 on page 12 of this paper is described on page 8.